Downloaded from Elcodis.com electronic components distributor

Document Number: 89939

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# TYPICAL APPLICATIONS

 $V_{BR}$ 

P<sub>PPM</sub> (10 x 1000 µs)

P<sub>D</sub> at T<sub>M</sub> = 65 °C

T<sub>J</sub> max.

**PRIMARY CHARACTERISTICS** 

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

### **FEATURES**

- Very low profile typical height of 0.95 mm
- Junction passivation optimzed design passivated RoHS anisotropic rectifier technology COMPLIANT
- HALOGEN T<sub>J</sub> = 185 °C capability suitable for high reliability FREE and automotive requirement
- Ideal for automated placement
- Uni-directional only
- Excellent clamping capability
- Peak pulse power: 600 W (10/1000 μs)
- AEC-Q101 gualified
- 15 kV (air)
- 8 kV (contact)
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

### **MECHANICAL DATA**

Case: DO-221AC (SlimSMA) Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	VALUE	UNIT		
Peak pulse power dissipation	with a 10/1000 µs waveform	P <sub>PPM</sub> <sup>(1)</sup>	600	W		
Peak pulse current	with a 10/1000 µs waveform	I <sub>PPM</sub> <sup>(1)</sup>	See next table	А		
Power dissipation on infinite heatsink, T <sub>4</sub>	P <sub>D</sub> <sup>(2)</sup>	6	w			
Power dissipation, $T_A = 25 \text{ °C}$	P <sub>D</sub> <sup>(3)</sup>	1.1				
Operating junction and storage temperat	$T_J$ , $T_STG$	- 65 to + 185	°C			

Notes

<sup>(1)</sup> Non-repetitive current pulse, per fig. 3 and derated above  $T_A = 25$  °C per fig. 2.

<sup>(2)</sup> Power dissipation mounted on infinite heatsink

<sup>(3)</sup> Power dissipation mounted on minimum recommended pad layout





TA6F6.8A thru TA6F51A

Vishay General Semiconductor

## Surface Mount PAR<sup>®</sup> Transient Voltage Suppressors High Temperature Stability and High Reliability Conditions

6.8 V to 51 V

600 W

6 W

185 °C

- ESD capability: IEC 61000-4-2 level 4
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)									
DEVICE TYPE	DEVICE MARKING CODE			TEST CURRENT I <sub>T</sub>	STAND-OFF VOLTAGE V <sub>WM</sub>	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub>	T <sub>J</sub> = 150 °C MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub>	MAXIMUM PEAK PULSE SURGE CURRENT	MAXIMUM CLAMPING VOLTAGE AT I <sub>PPM</sub>
		MIN. MAX.		I <sub>R</sub>	I <sub>R</sub>	I <sub>PPM</sub>	v <sub>c</sub>		
		v		mA	v	μΑ	μΑ	Α	v
TA6F6.8A	AEP	6.45	7.14	10	5.80	500	1000	57.1	10.5
TA6F7.5A	AGP	7.13	7.88	10	6.40	250	500	53.1	11.3
TA6F8.2A	AKP	7.79	8.61	10	7.02	100	200	49.6	12.1
TA6F9.1A	AMP	8.65	9.55	1.0	7.78	25	50	44.8	13.4
TA6F10A	APP	9.5	10.5	1.0	8.55	5.0	20	41.4	14.5
TA6F11A	ARP	10.5	11.6	1.0	9.40	2.0	5.0	38.5	15.6
TA6F12A	ATP	11.4	12.6	1.0	10.2	2.0	5.0	35.9	16.7
TA6F13A	AVP	12.4	13.7	1.0	11.1	2.0	5.0	33.0	18.2
TA6F15A	AXP	14.3	15.8	1.0	12.8	1.0	5.0	28.3	21.2
TA6F16A	AZP	15.2	16.8	1.0	13.6	1.0	5.0	26.7	22.5
TA6F18A	BEP	17.1	18.9	1.0	15.3	1.0	5.0	23.5	25.5
TA6F20A	BGP	19.0	21.0	1.0	17.1	1.0	5.0	21.7	27.7
TA6F22A	BKP	20.9	23.1	1.0	18.8	1.0	5.0	19.6	30.6
TA6F24A	BMP	22.8	25.2	1.0	20.5	1.0	5.0	18.1	33.2
TA6F27A	BPP	25.7	28.4	1.0	23.1	1.0	5.0	16.0	37.5
TA6F30A	BRP	28.5	31.5	1.0	25.6	1.0	5.0	14.5	41.4
TA6F33A	BTP	31.4	34.7	1.0	28.2	1.0	5.0	13.1	45.7
TA6F36A	BVP	34.2	37.8	1.0	30.8	1.0	5.0	12.0	49.9
TA6F39A	BXP	37.1	41.0	1.0	33.3	1.0	5.0	11.1	53.9
TA6F43A	BZP	40.9	45.2	1.0	36.8	1.0	10.0	10.1	59.3
TA6F47A	CEP	44.7	49.4	1.0	40.2	1.0	10.0	9.3	64.8
TA6F51A	CGP	48.5	53.6	1.0	43.6	1.0	10.0	8.6	70.1

#### Note

<sup>(1)</sup> Pulse test:  $t_p \le 50 \text{ ms}$ 

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient	R <sub>0JA</sub> <sup>(1)</sup>	145	°C/W			
Typical thermal resistance, junction to mount	R <sub>0JM</sub> (2)	20	°C/W			

#### Notes

<sup>(1)</sup> Mounted on minimum recommended pad layout

<sup>(2)</sup> Mounted on infinite heatsink

#### IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS

(T <sub>A</sub> = 25 °C unless otherwise noted)								
STANDARD TEST TYPE		TEST CONDITIONS	SYMBOL	CLASS	VALUE			
IEC 61000-4-2	Human body model (contact mode)	C = 150 pF, R = 330 Ω	V <sub>C</sub>	4	> 8 kV			
	Human body model (air discharge mode)	$0 = 150  \text{pr},  \text{m} = 350  \Omega$			> 15 kV			

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TA6F6.8AHM3/6A (1)	0.032	6A	3500	7" diameter plastic tape and reel			
TA6F6.8AHM3/6B <sup>(1)</sup>	0.032	6B	14 000	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

Revision: 10-Aug-12

Document Number: 89939



#### RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

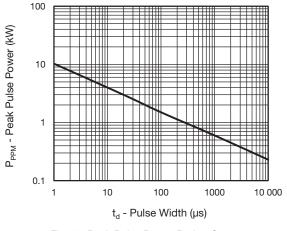


Fig. 1 - Peak Pulse Power Rating Curve

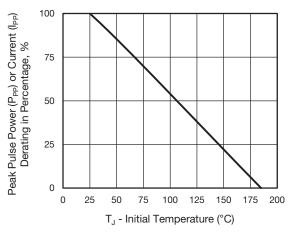
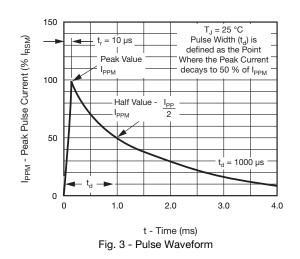
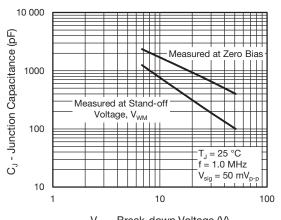


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

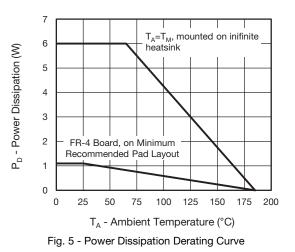


## Vishay General Semiconductor



 $V_{BR}$  - Break-down Voltage (V)





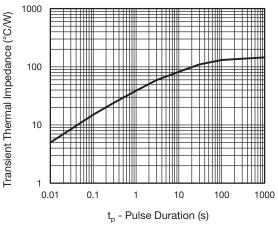


Fig. 6 - Typical Transient Thermal Impedance

Revision: 10-Aug-12

Document Number: 89939

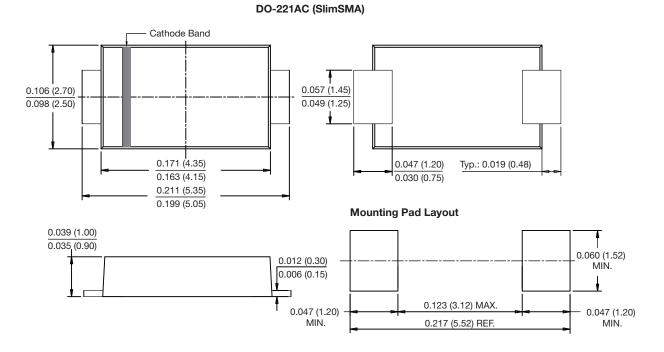
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



## Vishay General Semiconductor

www.vishay.com

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.